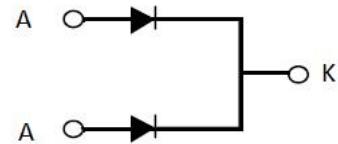


SCHOTTKY RECTIFIERS**Features:**

- High ESD capacity
- High junction temperature capability
- High frequency operation
- Low leakage current
- High surge capacity

**Applications:**

- Switching mode power supply
- High frequency inverter circuit
- Polarity protection circuit



Product Summary	
V_R	100 V
$I_F(AV)$	2*20A
T_j	150°C
$V_F(\text{max.})$	0.850V

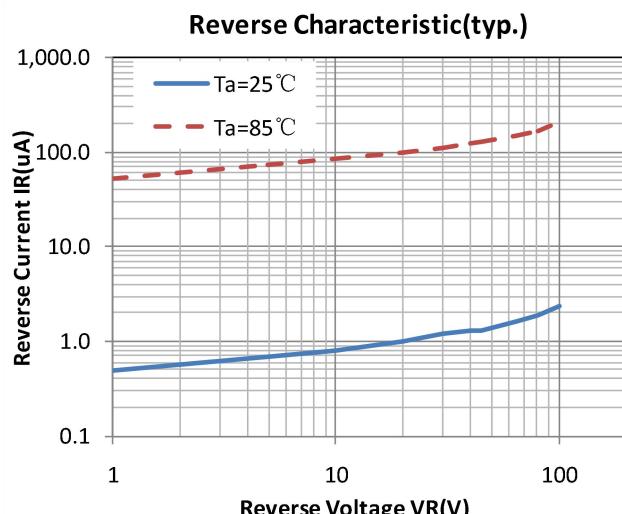
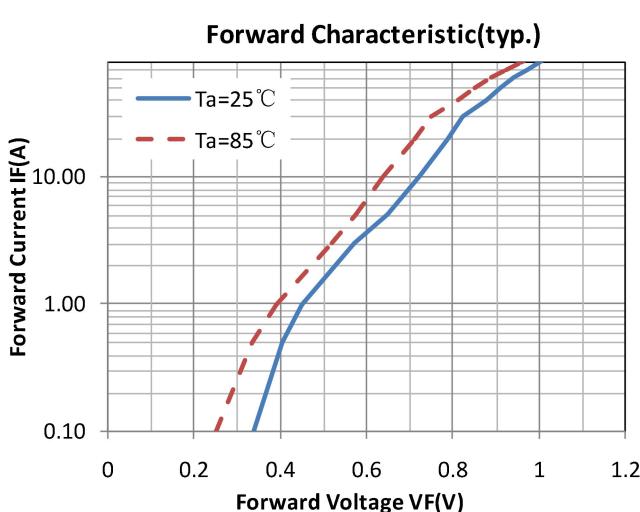
Absolute Maximum Ratings			
Parameter	Symbol	Values	Units
Repetitive peak reverse voltage	V_{RRM}	100	V
Continuous forward current	$I_F(AV)$	40	A
Single pulse forward current	I_{FSM}	200	
Operating junction	T_j	150	°C
Storage temperatures	T_{stg}	-55 to +150	°C
Peak Repetitive Reverse Surge Current	I_{RRM}	8	A

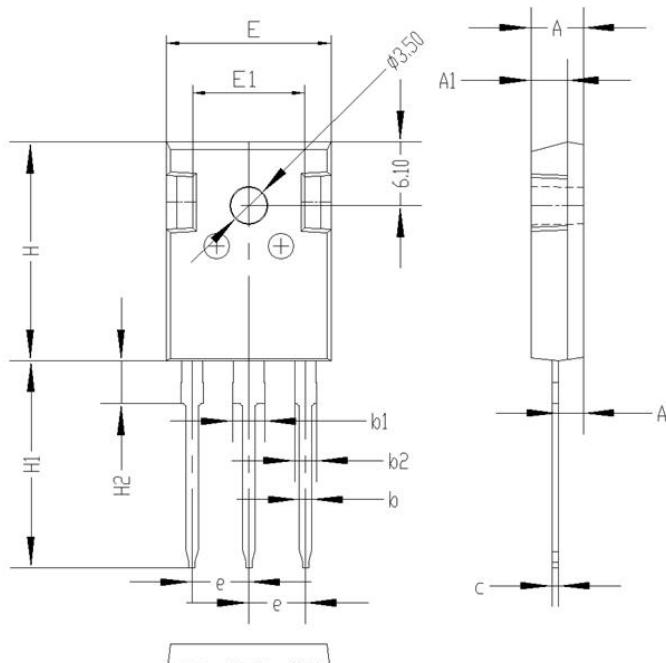
Electrical characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V _{BR} , V _R	I _R =100μA	100			V
Forward voltage (Per Diode)	V _F	I _F =20 A		0.785	0.850	
		I _F =20 A, T _j =85°C		0.710	0.800	
Reverse leakage current(Per Diode)	I _R	V _R = V _{RRM}			20	μA
		T _j =125°C , V _R =100V			10	mA

Thermal characteristics

Parameter	Symbol	Typ.	Units
Junction-to-Case	R _{θJC}	0.8	°C /W

Electrical performance (typic)


Package Information**TO-247 PACKAGE**

Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.80	5.20
A1	3.30	3.70
A2	2.10	2.50
b	1.00	1.40
b1	2.90	3.30
b2	1.90	2.30
c	0.40	0.80
e	5.25	5.65
E	15.6	16.0
E1	10.6	11.00
H	20.8	21.2
H1	19.4	20.4
H2	3.90	4.30
G	5.90	6.30
ΦP	3.30	3.70